

## Product Overview

The NSi8100 devices are high reliability bidirectional isolators that are compatible with I<sup>2</sup>C interface. The NSi8100 devices are safety certified by UL1577 support several insulation withstand voltages (3.75kV<sub>rms</sub>, 5kV<sub>rms</sub>), while providing high electromagnetic immunity and low emissions at low power consumption. The I<sup>2</sup>C clock of the NSi8100 is up to 2MHz, and the common-mode transient immunity (CMTI) is up to 150kV/us. Wide supply voltage of the NSi8100 device support to connect with most digital interface directly, easy to do the level shift. High system level EMC performance enhance reliability and stability of use.

## Key Features

- Up to 5000V<sub>rms</sub> Insulation voltage
- I<sup>2</sup>C Clock rate: up to 2MHz
- Power supply voltage: 2.5V to 5.5V
- High CMTI: 150kV/us
- Chip level ESD: HBM: ±6kV
- High system level EMC performance:  
Enhanced system level ESD, EFT, Surge immunity
- Low power consumption: 1.5mA/ch (1 Mbps)
- Low propagation delay: <15ns
- Operation temperature: -40°C~125°C
- RoHS-compliant packages:  
SOP8  
SOW16

## Safety Regulatory Approvals

- UL recognition: up to 5000V<sub>rms</sub> for 1 minute per UL1577
- CQC certification per GB4943.1-2011
- CSA component notice 5A
- DIN VDE V 0884-11:2017-01

## Applications

- Power over ethernet
- Isolated I<sup>2</sup>C, SMBus, or PMBus interface
- I<sup>2</sup>C level shifting
- Battery Management

## Device Information

| Part Number | Package | Body Size        |
|-------------|---------|------------------|
| NSi8100N    | SOP8    | 6.00mm × 5.00mm  |
| NSi8100W    | SOW16   | 10.30mm × 7.50mm |

## Functional Block Diagrams

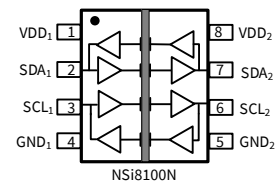


Figure 1. NSi8100N Block Diagram

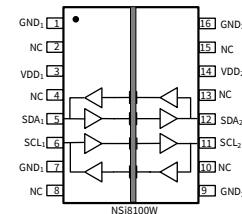


Figure 2. NSi8100W Block Diagram

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## 1. Package Information

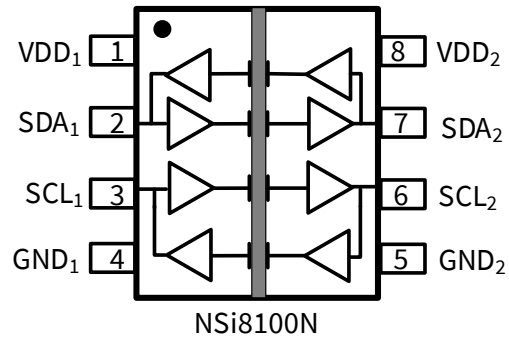


Figure 1.1 NSi8100N Package

Table1.1 NSi8100N Pin Configuration and Description

| NSi8100N PIN NO. | SYMBOL           | FUNCTION                                           |
|------------------|------------------|----------------------------------------------------|
| 1                | VDD <sub>1</sub> | Power Supply for Isolator Side 1                   |
| 2                | SDA <sub>1</sub> | Serial data input /output, Side 1                  |
| 3                | SCL <sub>1</sub> | Serial clock input /output, Side 1                 |
| 4                | GND <sub>1</sub> | Ground 1, the ground reference for Isolator Side 1 |
| 5                | GND <sub>2</sub> | Ground 2, the ground reference for Isolator Side 2 |
| 6                | SCL <sub>2</sub> | Serial clock input /output, Side 2                 |
| 7                | SDA <sub>2</sub> | Serial data input /output, Side 2                  |
| 8                | VDD <sub>2</sub> | Power Supply for Isolator Side 2                   |

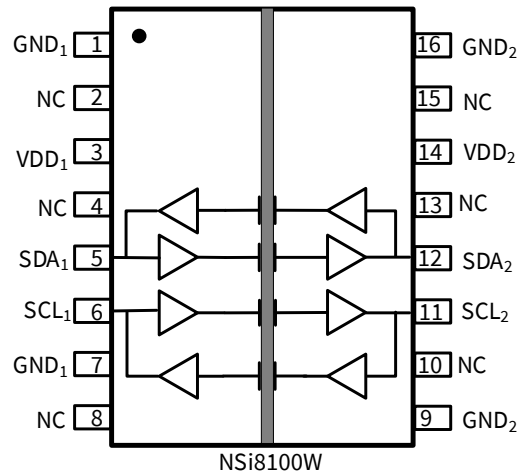


Figure 1.2 NSi8100W Package

Table1.2 NSi8100W Pin Configuration and Description

| <i>NSi8100W</i> PIN NO. | SYMBOL           | FUNCTION                                           |
|-------------------------|------------------|----------------------------------------------------|
| 1                       | GND <sub>1</sub> | Ground 1, the ground reference for Isolator Side 1 |
| 2                       | NC               | No Connection.                                     |
| 3                       | VDD <sub>1</sub> | Power Supply for Isolator Side 1                   |
| 4                       | NC               | No Connection.                                     |
| 5                       | SDA <sub>1</sub> | Serial data input /output, Side 1                  |
| 6                       | SCL <sub>1</sub> | Serial clock input /output, Side 1                 |
| 7                       | GND <sub>1</sub> | Ground 1, the ground reference for Isolator Side 1 |
| 8                       | NC               | No Connection.                                     |
| 9                       | GND <sub>2</sub> | Ground 2, the ground reference for Isolator Side 2 |
| 10                      | NC               | No Connection.                                     |
| 11                      | SCL <sub>2</sub> | Serial clock input /output, Side 2                 |
| 12                      | SDA <sub>2</sub> | Serial data input /output, Side 2                  |
| 13                      | NC               | No Connection.                                     |
| 14                      | VDD <sub>2</sub> | Power Supply for Isolator Side 2                   |
| 15                      | NC               | No Connection.                                     |
| 16                      | GND <sub>2</sub> | Ground 2, the ground reference for Isolator Side 2 |

## 2. Absolute Maximum Ratings

| Parameters                      | Symbol                                                                       | Min  | Typ | Max                  | Unit | Comments                                                                          |
|---------------------------------|------------------------------------------------------------------------------|------|-----|----------------------|------|-----------------------------------------------------------------------------------|
| Power Supply Voltage            | VDD1, VDD2                                                                   | -0.5 |     | 6.5                  | V    |                                                                                   |
| Maximum Input Voltage           | SDA <sub>1</sub> , SDA <sub>2</sub> ,<br>SCL <sub>1</sub> , SCL <sub>2</sub> | -0.4 |     | VDD+0.4 <sup>1</sup> | V    |                                                                                   |
| Maximum Input Pulse Voltage     | SDA <sub>1</sub> , SDA <sub>2</sub> ,<br>SCL <sub>1</sub> , SCL <sub>2</sub> | -0.8 |     | VDD+0.8              | V    | Pulse width should be less than 100ns, and the duty cycle should be less than 10% |
| Output current                  | I <sub>o</sub>                                                               | -15  |     | 15                   | mA   |                                                                                   |
| Maximum Surge Isolation Voltage | V <sub>IOSM</sub>                                                            |      |     | 5.3                  | kV   |                                                                                   |
| Operating Temperature           | T <sub>opr</sub>                                                             | -40  |     | 125                  | °C   |                                                                                   |
| Junction Temperature            | T <sub>j</sub>                                                               |      |     | 150                  | °C   |                                                                                   |
| Storage Temperature             | T <sub>stg</sub>                                                             | -65  |     | 150                  | °C   |                                                                                   |
| Electrostatic discharge         | HBM                                                                          |      |     | ±6000                | V    |                                                                                   |
|                                 | CDM                                                                          |      |     | ±2000                | V    |                                                                                   |

## 3. Recommended Operating Conditions

| Parameters                     | Symbol           | min                   | typ | max                   | unit |
|--------------------------------|------------------|-----------------------|-----|-----------------------|------|
| Power Supply Voltage           | VDD1, VDD2       | 2.5                   |     | 5.5                   | V    |
| Operating Temperature          | T <sub>opr</sub> | -40                   |     | 125                   | °C   |
| Side1 High Level Input Voltage | VIH1             | 0.6                   |     |                       | V    |
| Side1 Low Level Input Voltage  | VIL1             |                       |     | 0.4                   | V    |
| Side2 High Level Input Voltage | VIH2             | V <sub>DD2</sub> *0.7 |     |                       |      |
| Side2 Low Level Input Voltage  | VIL2             |                       |     | V <sub>DD2</sub> *0.3 |      |
| Data rate                      | DR               | 0                     |     | 2                     | Mbps |

## 4. Thermal Characteristics

| Parameters                            | Symbol          | SOW16 | SOP8  | Unit |
|---------------------------------------|-----------------|-------|-------|------|
| IC Junction-to-Air Thermal Resistance | θ <sub>JA</sub> | 86.5  | 137.7 | °C/W |

| Parameters                                | Symbol              | SOW16 | SOP8 | Unit |
|-------------------------------------------|---------------------|-------|------|------|
| Junction-to-case (top) thermal resistance | $\theta_{JC (top)}$ | 49.6  | 54.9 | °C/W |
| Junction-to-board thermal resistance      | $\theta_{JB}$       | 49.7  | 71.7 | °C/W |

## 5. Specifications

### 5.1. Electrical Characteristics

(VDD1=2.5V~5.5V, VDD2=2.5V~5.5V, Ta=-40°C to 125°C. Unless otherwise noted, Typical values are at VDD1 = 5V, VDD2 = 5V, Ta = 25°C)

| Parameters                                                                | Symbol               | Min                   | Typ  | Max                   | Unit  | Comments                                        |
|---------------------------------------------------------------------------|----------------------|-----------------------|------|-----------------------|-------|-------------------------------------------------|
| Power on Reset                                                            | VDD <sub>POR</sub>   |                       | 2.2  |                       | V     | POR threshold as during power-up                |
|                                                                           | VDD <sub>HYS</sub>   |                       | 0.1  |                       | V     | POR threshold Hysteresis                        |
| Start Up Time after POR                                                   | trbs                 |                       | 40   |                       | usec  |                                                 |
| Common Mode Transient Immunity                                            | CMTI                 | ±100                  | ±150 |                       | kV/us | See figure 5.8                                  |
| SDA, SCL logic low leakage                                                | IIL                  |                       |      | 15                    | uA    |                                                 |
| <b>Side 1 Logic Level</b>                                                 |                      |                       |      |                       |       |                                                 |
| Input Threshold                                                           | V <sub>ILT1</sub>    | 400                   |      |                       | mV    | Input Threshold at falling edge                 |
|                                                                           | V <sub>IHT1</sub>    |                       |      | 600                   | mV    | Input Threshold at rising edge                  |
|                                                                           | V <sub>IT_HYS1</sub> |                       | 100  |                       | mV    | Input Threshold Hysteresis                      |
| Low Level Output Voltage                                                  | V <sub>OL1</sub>     | 650                   |      | 800                   | mV    | I <sub>OL</sub> ≤ 4mA, R <sub>PULL UP</sub> =1K |
| Low-level output voltage to high-level input voltage threshold difference | ΔV <sub>OIT1</sub>   | 70                    |      |                       | mV    |                                                 |
| <b>Side 2 Logic Level</b>                                                 |                      |                       |      |                       |       |                                                 |
| High Level Input Voltage                                                  | V <sub>IH2</sub>     | V <sub>DD2</sub> *0.7 |      |                       | V     |                                                 |
| Low Level Input Voltage                                                   | V <sub>IL2</sub>     |                       |      | V <sub>DD2</sub> *0.3 | V     |                                                 |
| Low Level Output Voltage                                                  | V <sub>OL</sub>      |                       |      | 0.5                   | V     | I <sub>OL</sub> ≤ 30mA                          |

(VDD1=5V± 10%, VDD2=5V± 10%, Ta=-40°C to 125°C. Unless otherwise noted, Typical values are at VDD1 = 5V, VDD2 = 5V, Ta = 25°C)

| Parameters | Symbol                | Min | Typ  | Max | Unit | Comments     |
|------------|-----------------------|-----|------|-----|------|--------------|
|            | I <sub>DD1</sub> (Q0) |     | 5.10 | 7.5 | mA   | All Input 0V |

|                        |                       |   |      |      |     |                                                                |
|------------------------|-----------------------|---|------|------|-----|----------------------------------------------------------------|
|                        | I <sub>DD2</sub> (Q0) |   | 3.96 | 5.7  | mA  | All Input at supply                                            |
|                        | I <sub>DD1</sub> (Q1) |   | 2.52 | 3.6  | mA  |                                                                |
|                        | I <sub>DD2</sub> (Q1) |   | 1.78 | 2.5  | mA  |                                                                |
|                        | I <sub>DD1</sub> (2M) |   | 3.83 | 5.7  | mA  | All Input with 2MHz,<br>C <sub>L</sub> =15pF                   |
|                        | I <sub>DD2</sub> (2M) |   | 2.78 | 4.2  | mA  |                                                                |
| Clock rate             | DR                    | 0 |      | 2    | MHz |                                                                |
| Propagation Delay      | t <sub>PLH12</sub>    |   | 24.8 | 37.2 | ns  | See <a href="#">figure 5.7</a> , R1=1500Ω,<br>R2=500Ω, NO LOAD |
|                        | t <sub>PHL12</sub>    |   | 32.8 | 49.2 | ns  | See <a href="#">figure 5.7</a> , R1=1500Ω,<br>R2=500Ω, NO LOAD |
|                        | t <sub>PLH21</sub>    |   | 24   | 36   | ns  | See <a href="#">figure 5.7</a> , R1=1500Ω,<br>R2=500Ω, NO LOAD |
|                        | t <sub>PHL21</sub>    |   | 38   | 57   | ns  | See <a href="#">figure 5.7</a> , R1=1500Ω,<br>R2=500Ω, NO LOAD |
| Pulse Width Distortion | PWD <sub>12</sub>     |   | 8    | 12   | ns  | t <sub>PHL12</sub> – t <sub>PLH12</sub>                        |
|                        | PWD <sub>21</sub>     |   | 14   | 21   | ns  | t <sub>PHL21</sub> – t <sub>PLH21</sub>                        |
| Falling Time           | t <sub>f1</sub>       |   | 10.6 | 15.9 | ns  | C <sub>L</sub> = 30pF                                          |
|                        | t <sub>f2</sub>       |   | 22.8 | 34.2 | ns  | C <sub>L</sub> = 300pF                                         |

(VDD1=3.3V± 10%, VDD2=3.3V± 10%, Ta=-40°C to 125°C. Unless otherwise noted, Typical values are at VDD1 = 3.3V, VDD2 = 3.3V, Ta = 25°C)

| Parameters        | Symbol                | Min | Typ  | Max  | Unit | Comments                                                       |
|-------------------|-----------------------|-----|------|------|------|----------------------------------------------------------------|
|                   | I <sub>DD1</sub> (Q0) |     | 4.96 | 7.4  | mA   | All Input 0V                                                   |
|                   | I <sub>DD2</sub> (Q0) |     | 3.85 | 5.6  | mA   |                                                                |
|                   | I <sub>DD1</sub> (Q1) |     | 2.40 | 3.5  | mA   | All Input at supply                                            |
|                   | I <sub>DD2</sub> (Q1) |     | 1.68 | 2.4  | mA   |                                                                |
|                   | I <sub>DD1</sub> (2M) |     | 3.69 | 5.6  | mA   | All Input with 2MHz,<br>C <sub>L</sub> =15pF                   |
|                   | I <sub>DD2</sub> (2M) |     | 2.67 | 4.2  | mA   |                                                                |
| Clock rate        | DR                    | 0   |      | 2    | MHz  |                                                                |
| Propagation Delay | t <sub>PLH12</sub>    |     | 29   | 43.5 | ns   | See <a href="#">figure 5.7</a> , R1=1500Ω,<br>R2=500Ω, NO LOAD |
|                   | t <sub>PHL12</sub>    |     | 39.8 | 59.7 | ns   | See <a href="#">figure 5.7</a> , R1=1500Ω,<br>R2=500Ω, NO LOAD |

|                        |             |  |      |      |    |                                                             |
|------------------------|-------------|--|------|------|----|-------------------------------------------------------------|
|                        | $t_{PLH21}$ |  | 30   | 45   | ns | See <a href="#">figure 5.7</a> , R1=1500Ω, R2=500Ω, NO LOAD |
|                        | $t_{PHL21}$ |  | 61   | 91.5 | ns | See <a href="#">figure 5.7</a> , R1=1500Ω, R2=500Ω, NO LOAD |
| Pulse Width Distortion | $PWD_{12}$  |  | 10.8 | 16.2 | ns | $ t_{PHL12} - t_{PLH12} $                                   |
|                        | $PWD_{21}$  |  | 31   | 46.5 | ns | $ t_{PHL21} - t_{PLH21} $                                   |
| Falling Time           | $t_{f1}$    |  | 15.6 | 23.4 | ns | $C_L = 30pF$                                                |
|                        | $t_{f2}$    |  | 32   | 48   | ns | $C_L = 300pF$                                               |

(VDD1=2.5V± 10%, VDD2=2.5V± 10%, Ta=-40°C to 125°C. Unless otherwise noted, Typical values are at VDD1 = 2.5V, VDD2 = 2.5V, Ta = 25°C)

| Parameters             | Symbol        | Min | Typ  | Max  | Unit | Comments                                                    |
|------------------------|---------------|-----|------|------|------|-------------------------------------------------------------|
|                        | $I_{DD1}(Q0)$ |     | 4.89 | 7.3  | mA   | All Input 0V                                                |
|                        | $I_{DD2}(Q0)$ |     | 3.79 | 5.5  | mA   |                                                             |
|                        | $I_{DD1}(Q1)$ |     | 2.34 | 3.4  | mA   | All Input at supply                                         |
|                        | $I_{DD2}(Q1)$ |     | 1.63 | 2.3  | mA   |                                                             |
|                        | $I_{DD1}(2M)$ |     | 3.61 | 5.4  | mA   | All Input with 2MHz,<br>$C_L=15pF$                          |
|                        | $I_{DD2}(2M)$ |     | 2.59 | 4    | mA   |                                                             |
| Clock rate             | DR            | 0   |      | 2    | MHz  |                                                             |
| Propagation Delay      | $t_{PLH12}$   |     | 33   | 49.5 | ns   | See <a href="#">figure 5.7</a> , R1=1500Ω, R2=500Ω, NO LOAD |
|                        | $t_{PHL12}$   |     | 52   | 78   | ns   | See <a href="#">figure 5.7</a> , R1=1500Ω, R2=500Ω, NO LOAD |
|                        | $t_{PLH21}$   |     | 47   | 70.5 | ns   | See <a href="#">figure 5.7</a> , R1=1500Ω, R2=500Ω, NO LOAD |
|                        | $t_{PHL21}$   |     | 100  | 150  | ns   | See <a href="#">figure 5.7</a> , R1=1500Ω, R2=500Ω, NO LOAD |
| Pulse Width Distortion | $PWD_{12}$    |     | 19   | 28.5 | ns   | $ t_{PHL12} - t_{PLH12} $                                   |
|                        | $PWD_{21}$    |     | 53   | 79.5 | ns   | $ t_{PHL21} - t_{PLH21} $                                   |
| Falling Time           | $t_{f1}$      |     | 22   | 33   | ns   | $C_L = 30pF$                                                |
|                        | $t_{f2}$      |     | 36   | 54   | ns   | $C_L = 300pF$                                               |

## 5.2. Typical Performance Characteristics

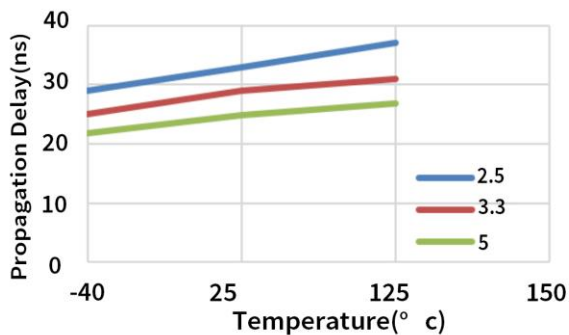


Figure 5.1 Side1 to Side2 Rising Edge Propagation Delay Vs Temp

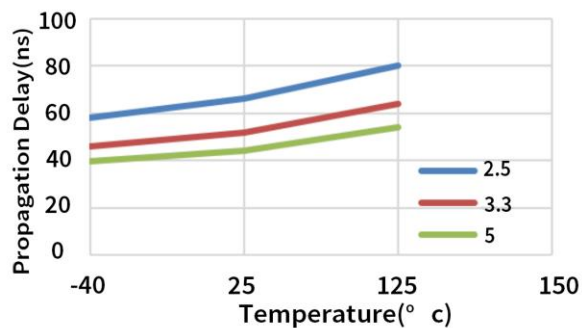


Figure 5.2 Side1 to Side2 Falling Edge Propagation Delay Vs Temp

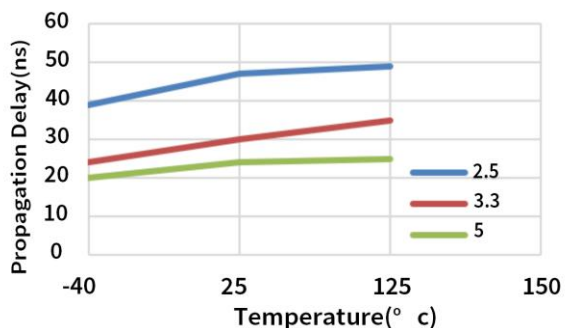


Figure 5.3 Side2 to Side1 Rising Edge Propagation Delay Vs Temp

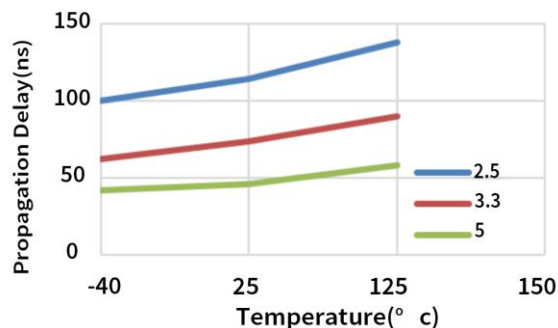


Figure 5.4 Side2 to Side1 Falling Edge Propagation Delay Vs Temp

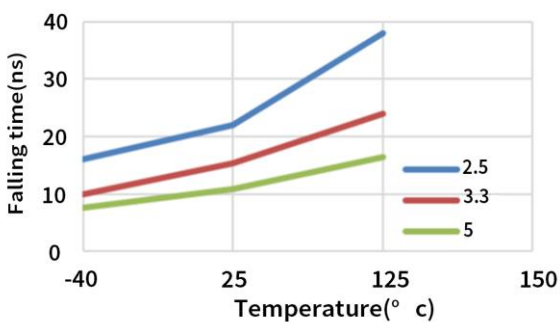


Figure 5.5 Falling time(@27pF) Vs Temp

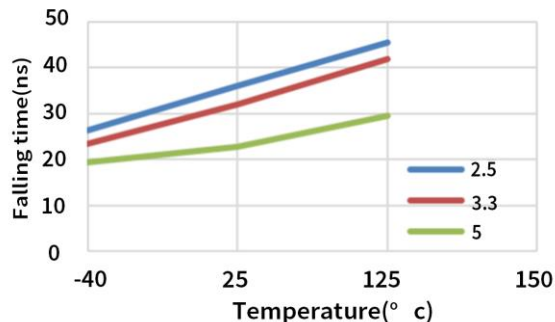


Figure 5.6 Falling time(@300pF) Vs Temp

## 5.3. Parameter Measurement Information

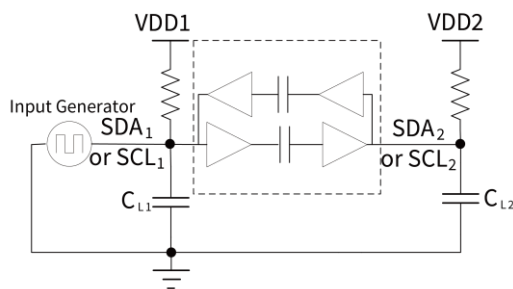


Figure 5.7 Switching Characteristic Test Circuit and Voltage Waveforms

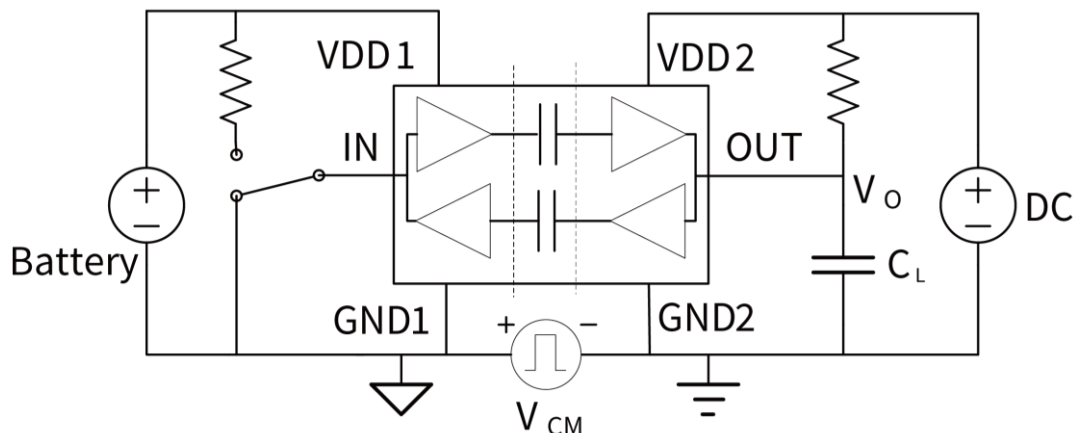


Figure 5.8 Common-Mode Transient Immunity Test Circuit

## 6. High Voltage Feature Description

### 6.1. Insulation and Safety Related Specifications

| Description                                                          | Test Condition                                                                                                                                | Symbol              | Value     |           | Unit              |
|----------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------|---------------------|-----------|-----------|-------------------|
|                                                                      |                                                                                                                                               |                     | SOP8      | SOW16     |                   |
| Minimum External Air Gap (Clearance)                                 |                                                                                                                                               | L(I01)              | 4.0       | 8.0       | mm                |
| Minimum External Tracking (Creepage)                                 |                                                                                                                                               | L(I02)              | 4.0       | 8.0       | mm                |
| Distance through the Insulation                                      |                                                                                                                                               | DTI                 | 20        |           | um                |
| Comparative Tracking Index                                           | DIN EN 60112 (VDE 0303-11)                                                                                                                    | CTI                 | >400      |           | V                 |
| Material Group                                                       | IEC 60112                                                                                                                                     |                     | II        |           |                   |
| Installation Classification per DIN VDE 0110                         |                                                                                                                                               |                     |           |           |                   |
| For Rated Mains Voltage ≤ 150V <sub>rms</sub>                        |                                                                                                                                               |                     | I to IV   | I to IV   |                   |
| For Rated Mains Voltage ≤ 300V <sub>rms</sub>                        |                                                                                                                                               |                     | I to III  | I to IV   |                   |
| For Rated Mains Voltage ≤ 400V <sub>rms</sub>                        |                                                                                                                                               |                     | I to III  | I to IV   |                   |
| Insulation Specification per DIN VDE V 0884-11:2017-01 <sup>1)</sup> |                                                                                                                                               |                     |           |           |                   |
| Climatic Classification                                              |                                                                                                                                               |                     | 10/105/21 | 10/105/21 |                   |
| Pollution Degree                                                     | per DIN VDE 0110, Table 1                                                                                                                     |                     | 2         | 2         |                   |
| Maximum repetitive isolation voltage                                 |                                                                                                                                               | V <sub>IORM</sub>   | 565       | 1166      | V <sub>peak</sub> |
| Maximum working isolation voltage                                    | AC                                                                                                                                            | V <sub>IOWM</sub>   | 400       | 824       | V <sub>rms</sub>  |
|                                                                      | DC                                                                                                                                            |                     | 565       | 1166      | V <sub>peak</sub> |
| Input to Output Test Voltage, Method B1                              | V <sub>IORM</sub> × 1. 5 = V <sub>pd (m)</sub> , 100% production test,<br>t <sub>ini</sub> = t <sub>m</sub> = 1 sec, partial discharge < 5 pC | V <sub>pd (m)</sub> | 847       | 1749      | V <sub>peak</sub> |

|                                                                                                            |                                                                                                          |             |          |          |            |
|------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------|-------------|----------|----------|------------|
| Input to Output Test Voltage, Method A.<br>After Environmental Tests Subgroup 1                            | $V_{IORM} \times 1.2 = V_{pd(m)}$ , $t_{ini} = 60$<br>sec, $t_m = 10$ sec, partial<br>discharge $< 5$ pC | $V_{pd(m)}$ | 678      | 1399     | $V_{peak}$ |
| Input to Output Test Voltage, Method A.<br>After Input and Output Safety Test<br>Subgroup 2 and Subgroup 3 | $V_{IORM} \times 1.2 = V_{pd(m)}$ , $t_{ini} = 60$<br>sec, $t_m = 10$ sec, partial<br>discharge $< 5$ pC | $V_{pd(m)}$ | 678      | 1399     | $V_{peak}$ |
| Maximum transient isolation voltage                                                                        | $t = 60$ sec                                                                                             | $V_{IOTM}$  | 5300     | 7000     | $V_{peak}$ |
| Maximum Surge Isolation Voltage                                                                            | Test method per<br>IEC60065, 1.2/50us<br>waveform, $V_{TEST} = 1.3 \times V_{IOSM}$                      | $V_{IOSM}$  | 5384     | 5384     | $V_{peak}$ |
| Isolation resistance                                                                                       | $V_{IO} = 500V$                                                                                          | $R_{IO}$    | $> 10^9$ | $> 10^9$ | $\Omega$   |
| Isolation capacitance                                                                                      | $f = 1MHz$                                                                                               | $C_{IO}$    | 0.6      | 0.6      | pF         |
| Insulation Specification per UL1577                                                                        |                                                                                                          |             |          |          |            |
| Withstand Isolation Voltage                                                                                | $V_{TEST} = 1.2 \times V_{ISO}$ , $t = 1$ sec,<br>100% production test                                   | $V_{ISO}$   | 3750     | 5000     | $V_{rms}$  |

- 1) This coupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

## 6.2. Safety-Limiting Values

Basic isolation safety-limiting values as outlined in VDE-0884-11 of NSi8100N(SOP8)

| Description                      | Test Condition                                                                                 | Value | Unit       |
|----------------------------------|------------------------------------------------------------------------------------------------|-------|------------|
| Safety Supply Power              | $R_{\theta JA} = 137.7^\circ C/W^{1)}$ , $T_J = 150^\circ C$ , $T_A = 25^\circ C$              | 907   | mW         |
| Safety Supply Current            | $R_{\theta JA} = 137.7^\circ C/W^{1)}$ , $V_I = 5V$ , $T_J = 150^\circ C$ , $T_A = 25^\circ C$ | 181   | mA         |
| Safety Temperature <sup>2)</sup> |                                                                                                | 150   | $^\circ C$ |

- 1) Calculate with the junction-to-air thermal resistance,  $R_{\theta JA}$ , of SOP8 package ([Thermal Information Table](#)) which is that of a device installed on a low effective thermal conductivity test board (1s) according to JESD51-3.
- 2) The maximum safety temperature has the same value as the maximum junction temperature ( $T_J$ ) specified for the device.

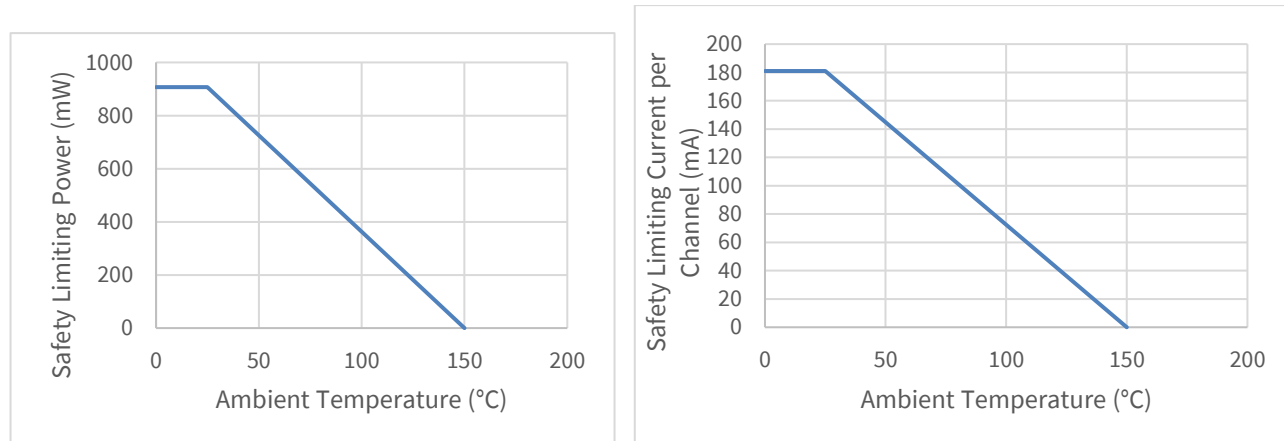


Figure 6.1 NSi8100N Thermal Derating Curve, Dependence of Safety Limiting Values with Case Temperature per DIN VDE V 0884-11

Basic isolation safety-limiting values as outlined in VDE-0884-11 of NSi8100W(SOW16)

| Description                      | Test Condition                                                                                                                       | Value | Unit |
|----------------------------------|--------------------------------------------------------------------------------------------------------------------------------------|-------|------|
| Safety Supply Power              | $R_{\theta JA} = 86.5^{\circ}\text{C}/\text{W}^{(1)}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$                     | 1445  | mW   |
| Safety Supply Current            | $R_{\theta JA} = 86.5^{\circ}\text{C}/\text{W}^{(1)}$ , $V_I = 5\text{V}$ , $T_J = 150^{\circ}\text{C}$ , $T_A = 25^{\circ}\text{C}$ | 289   | mA   |
| Safety Temperature <sup>2)</sup> |                                                                                                                                      | 150   | °C   |

- 1) Calculate with the junction-to-air thermal resistance,  $R_{\theta JA}$ , of SOW16 package ([Thermal Information Table](#)) which is that of a device installed on a low effective thermal conductivity test board (1s) according to JESD51-3.
- 2) The maximum safety temperature has the same value as the maximum junction temperature ( $T_J$ ) specified for the device.

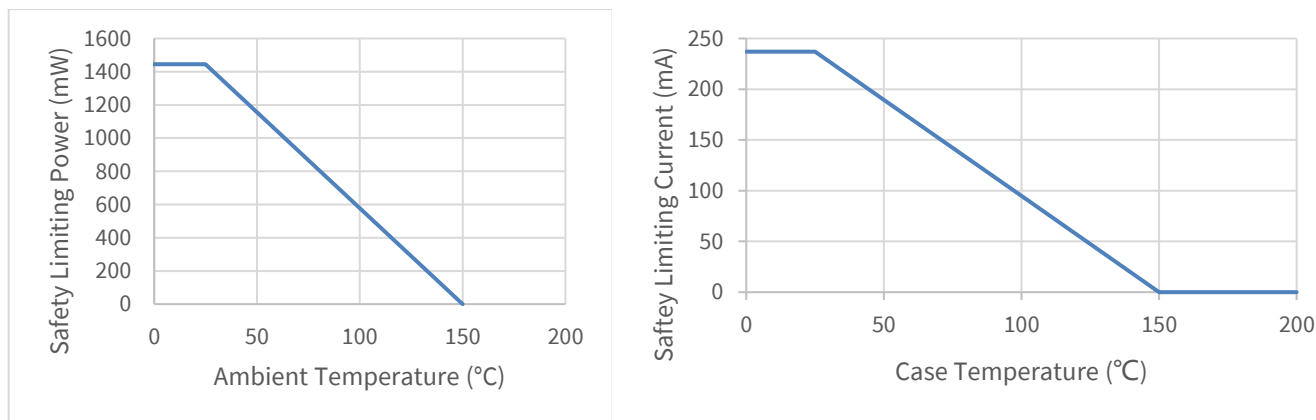


Figure 6.2 NSi8100W Thermal Derating Curve, Dependence of Safety Limiting Values with Case Temperature per DIN VDE V 0884-11

### 6.3. Regulatory Information

The NSi8100N are approved by the organizations listed in table.

| <i>CUL</i>                                                |                                                           | <i>VDE</i>                                                                          | <i>CQC</i>                                      |
|-----------------------------------------------------------|-----------------------------------------------------------|-------------------------------------------------------------------------------------|-------------------------------------------------|
| UL 1577 Component Recognition Program                     | Approved under CSA Component Acceptance Notice 5A         | DIN VDE V 0884-11(VDE V 0884-11):2017-01                                            | Certified by CQC11-471543-2012<br>GB4943.1-2011 |
| Single Protection, 3750V <sub>rms</sub> Isolation voltage | Single Protection, 3750V <sub>rms</sub> Isolation voltage | Basic Insulation 565V <sub>peak</sub> ,<br>V <sub>IOSM</sub> =5384V <sub>peak</sub> | Basic insulation                                |
| File (E500602)                                            | File (E500602)                                            | File (5024579-4880-0001)                                                            | File (pending)                                  |

The NSi8100W are approved by the organizations listed in table.

| <i>CUL</i>                                                |                                                           | <i>VDE</i>                                                                          | <i>CQC</i>                                      |
|-----------------------------------------------------------|-----------------------------------------------------------|-------------------------------------------------------------------------------------|-------------------------------------------------|
| UL 1577 Component Recognition Program <sup>1</sup>        | Approved under CSA Component Acceptance Notice 5A         | DIN VDE V 0884-11(VDE V 0884-11):2017-01 <sup>2</sup>                               | Certified by CQC11-471543-2012<br>GB4943.1-2011 |
| Single Protection, 5000V <sub>rms</sub> Isolation voltage | Single Protection, 5000V <sub>rms</sub> Isolation voltage | Basic Insulation 849V <sub>peak</sub> ,<br>V <sub>IOSM</sub> =5384V <sub>peak</sub> | Basic insulation                                |
| File (E500602)                                            | File (E500602)                                            | File (5024579-4880-0001)                                                            | File (pending)                                  |

## 7. Function Description

The NSI8100 is a bidirectional isolator based on a capacitive isolation barrier technique. The NSI8100 devices are compatible with I<sup>2</sup>C interface. Internally, the I<sup>2</sup>C interface is split into two unidirectional channels communicating in opposing directions via a dedicated capacitive isolation channel for each. The digital signal is modulated with RF carrier generated by the internal oscillator at the Transmitter side. Then it is transferred through the capacitive isolation barrier and demodulated at the Receiver side.

The NSi8100 devices are high reliability dual-channel bidirectional isolators for clock and data lines. The NSi8100 is suitable for multi-master application.

The Side 2 logic levels of NSi8100 are standard I<sup>2</sup>C value, and the maximum load for side 2 is ≤ 400pF. So multiple NSi8100 devices connected to a bus by their Side 2 pins can communicate with each other and with other I<sup>2</sup>C compatible devices.

The Side 1 logic levels of NSi8100 are not standard value. The output low level of NSi8100 is 650mV, while low-level output voltage to high-level input voltage threshold is 50mV. This prevents an output logic low at Side 1 being transmitted back to Side 2 and pulling down the I<sup>2</sup>C bus.

The NSi8100 device is safety certified by UL1577 support several insulation withstand voltages (3.75kV<sub>rms</sub>, 5kV<sub>rms</sub>), while providing high electromagnetic immunity and low emissions at low power consumption. The I<sup>2</sup>C clock of the NSi8100 is up to 2MHz, and the common-mode transient immunity (CMTI) is up to 150kV/us. Wide supply voltage of the NSi8100 device support to connect with most digital interface directly, easy to do the level shift. High system level EMC performance enhance reliability and stability of use.

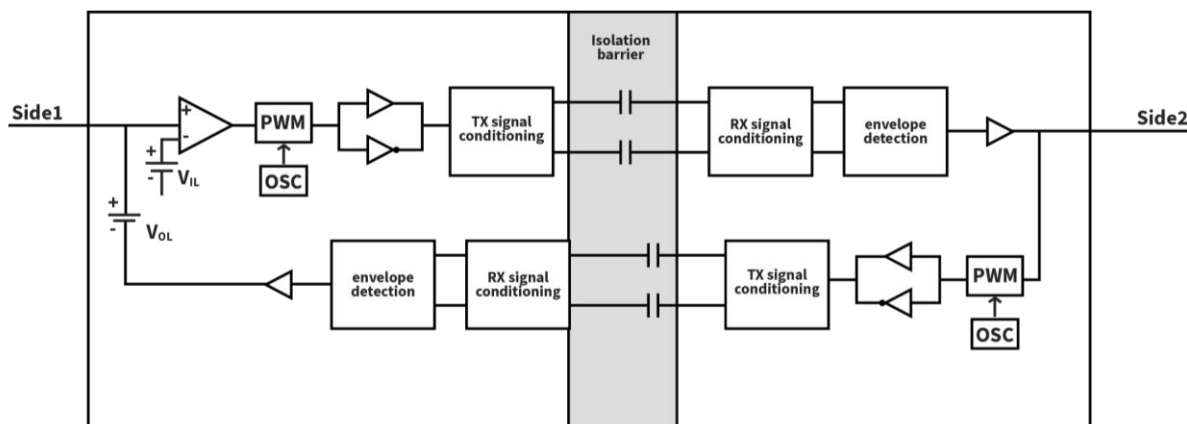


Figure 7.1 Simplified Channel Diagram

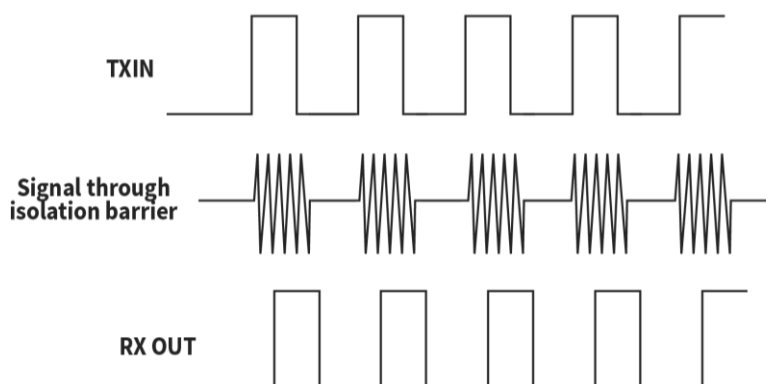


Figure 7.2 OOK Based Modulation Scheme

The Table 7.1 shows the functional of NSi8100. The NSi8100 is high impedance output when VDDIN is unready and VDDOUT is ready as shown in.

Table 7.1 Output status vs. power status

| Input | VDD1 status | VDD2 status | Output | Comment                                                                                             |
|-------|-------------|-------------|--------|-----------------------------------------------------------------------------------------------------|
| H     | Ready       | Ready       | Z      | Normal operation.                                                                                   |
| L     | Ready       | Ready       | L      |                                                                                                     |
| X     | Unready     | Ready       | Z      | The output follows the same status with the input within 60us after input side VDD1 is powered on.  |
| X     | Ready       | Unready     | X      | The output follows the same status with the input within 60us after output side VDD2 is powered on. |

## 8. Application Note

### 8.1. PCB Layout

The NSi8100 requires a 0.1  $\mu$ F bypass capacitor between VDD1 and GND1, VDD2 and GND2. The capacitor should be placed as close as possible to the package. Figure 8.1 to Figure 8.4 show the recommended PCB layout, make sure the space under the chip should keep free from planes, traces, pads and via. The pull-up resistors required for both Side 1 and Side 2 buses. And the value of the resistors depend on the number of I<sup>2</sup>C devices on the bus.

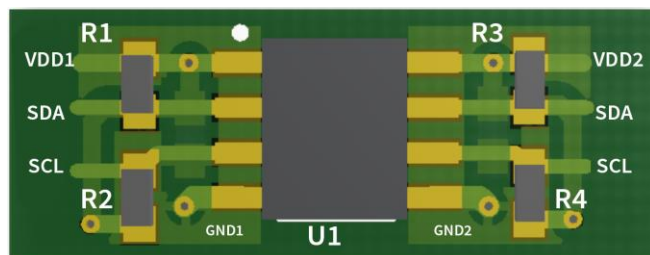


Figure8.1 Recommended PCB Layout — Top Layer



Figure8.2 Recommended PCB Layout — Bottom Layer

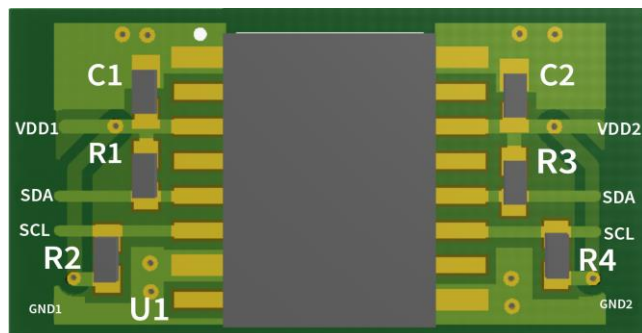


Figure8.3 Recommended PCB Layout — Top Layer



Figure8.4 Recommended PCB Layout — Bottom Layer

## 9. Package Information

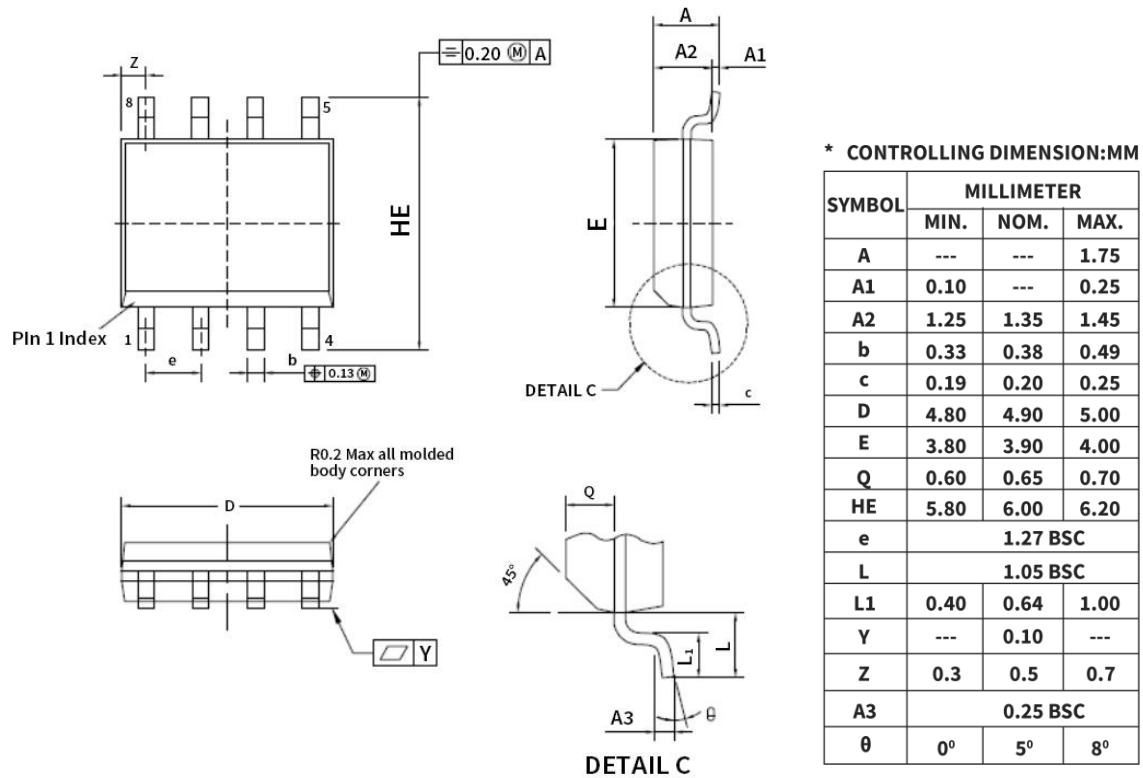


Figure 9.1 SOP8 Package Shape and Dimension in millimeters

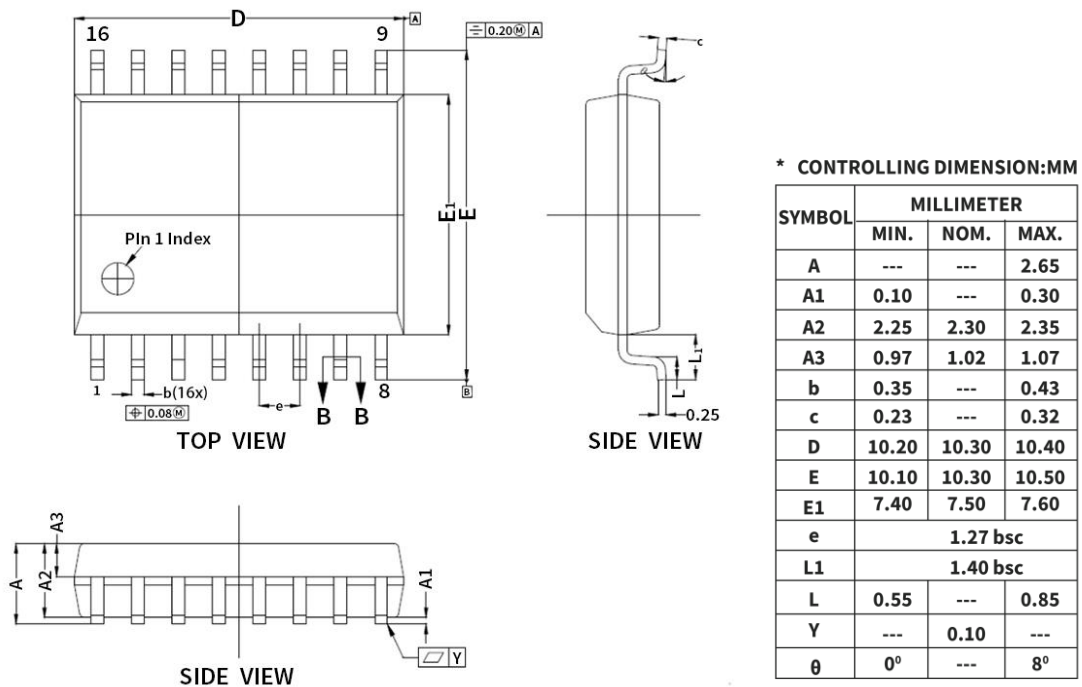


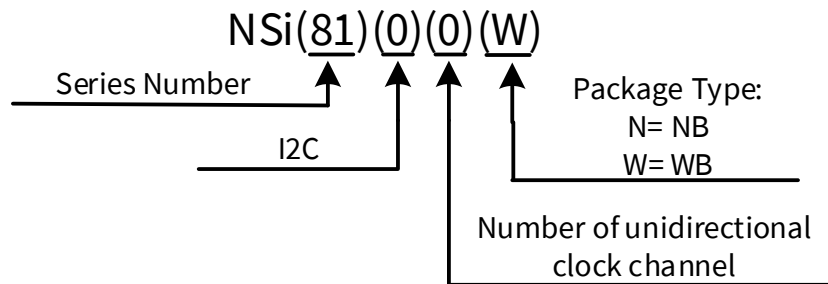
Figure 9.2 SOW16 Package Shape and Dimension in millimeters

## 10. Order Information

| Part No. | Isolation Rating(kV) | Number of side 1 inputs | Number of side 2 inputs | Max Clock Rate (MHz) | Operating Temperature | MSL | Automotive | Package | SPQ  |
|----------|----------------------|-------------------------|-------------------------|----------------------|-----------------------|-----|------------|---------|------|
| NSi8100N | 3.75                 | 2                       | 2                       | 2                    | -40 to 125°C          | 1   | NO         | SOP8    | 2500 |
| NSi8100W | 5                    | 2                       | 2                       | 2                    | -40 to 125°C          | 2   | NO         | SOW16   | 1000 |

NOTE: All packages are RoHS-compliant with peak reflow temperatures of 260 °C according to the JEDEC industry standard classifications and peak solder temperatures.

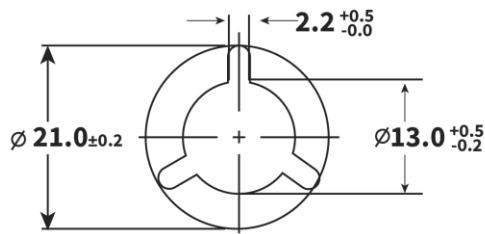
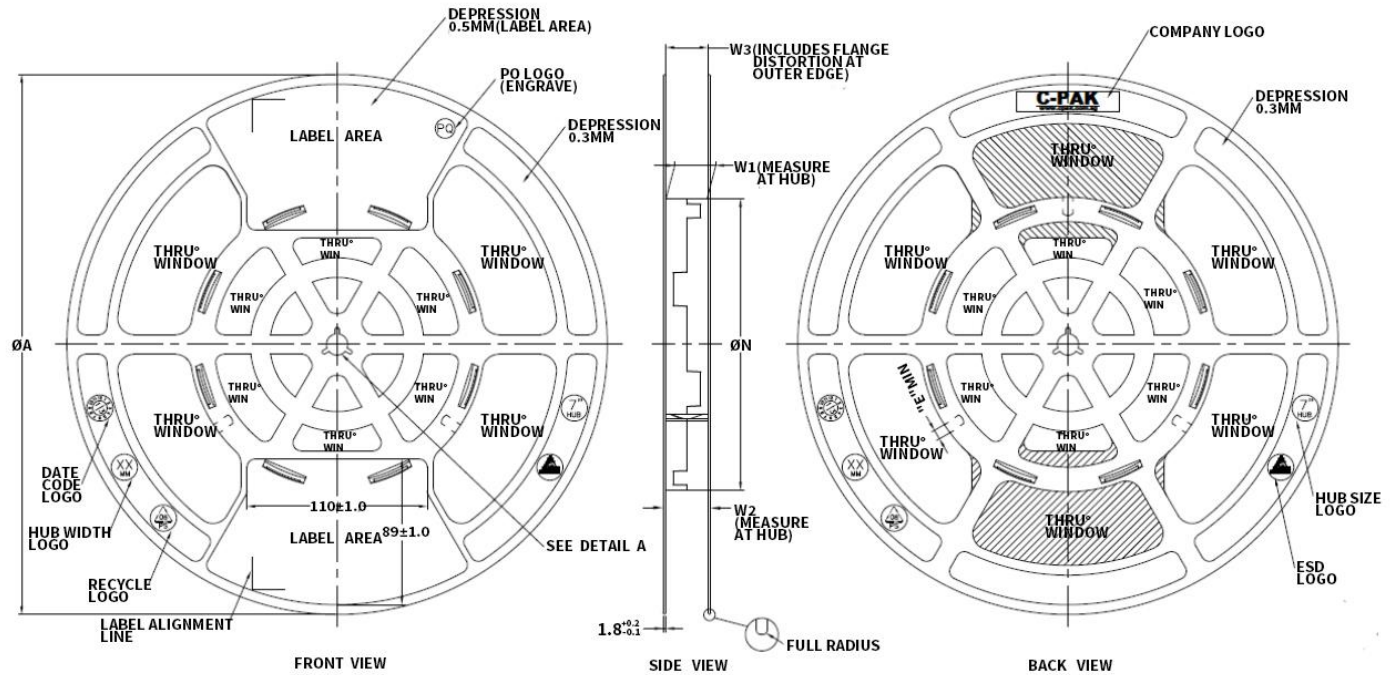
### Part Number Rule:



## 11. Documentation Support

| Part Number | Product Folder | Datasheet | Technical Documents | Isolator selection guide |
|-------------|----------------|-----------|---------------------|--------------------------|
| NSi8100     | tbd            | tbd       | tbd                 | tbd                      |

## 12. Tape and Reel Information



**ARBOR HOLE  
DETAIL A  
SCALE: 3:1**

| PRODUCT SPECIFICATION |             |             |                                      |             |                                                               |            |
|-----------------------|-------------|-------------|--------------------------------------|-------------|---------------------------------------------------------------|------------|
| TAPE WIDTH            | Ø A<br>±2.0 | Ø N<br>±2.0 | W1                                   | W2<br>(Max) | W3                                                            | E<br>(MIN) |
| 08MM                  | 330         | 178         | 8.4 <sup>+1.5</sup> <sub>-0.0</sub>  | 14.4        | SHALL<br>ACCOMMODATE<br>TAPE WIDTH<br>WITHOUT<br>INTERFERENCE | 5.5        |
| 12MM                  | 330         | 178         | 12.4 <sup>+2.0</sup> <sub>-0.0</sub> | 18.4        |                                                               | 5.5        |
| 16MM                  | 330         | 178         | 16.4 <sup>+2.0</sup> <sub>-0.0</sub> | 22.4        |                                                               | 5.5        |
| 24MM                  | 330         | 178         | 24.4 <sup>+2.0</sup> <sub>-0.0</sub> | 30.4        |                                                               | 5.5        |
| 32MM                  | 330         | 178         | 32.4 <sup>+2.0</sup> <sub>-0.0</sub> | 38.4        |                                                               | 5.5        |

| SURFACE RESISTIVITY |                                         |                     |            |
|---------------------|-----------------------------------------|---------------------|------------|
| LEGEND              | SR RANGE                                | TYPE                | COLOUR     |
| A                   | BELOW 10 <sup>12</sup>                  | ANTISTATIC          | ALL TYPES  |
| B                   | 10 <sup>6</sup> TO 10 <sup>11</sup>     | STATIC DISSIPATIVE  | BLACK ONLY |
| C                   | 10 <sup>5</sup> & BELOW 10 <sup>5</sup> | CONDUCTIVE(GENERIC) | BLACK ONLY |
| E                   | 10 <sup>9</sup> TO 10 <sup>11</sup>     | ANTISTATIC(COATED)  | ALL TYPES  |

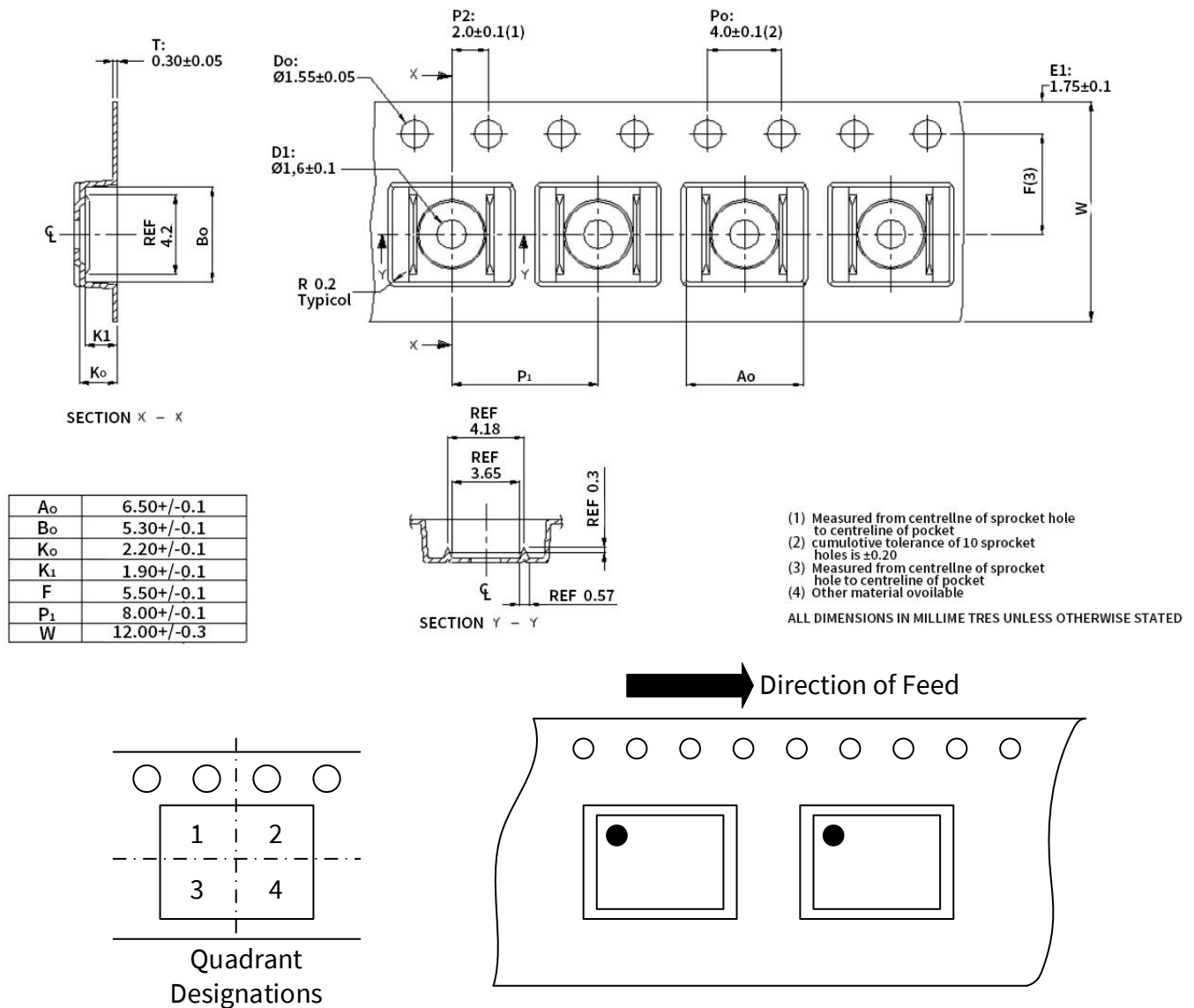
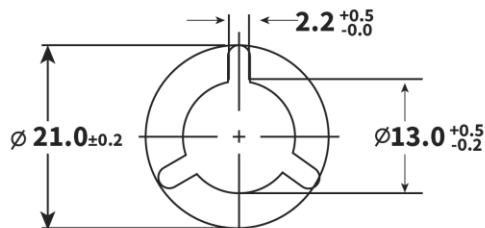
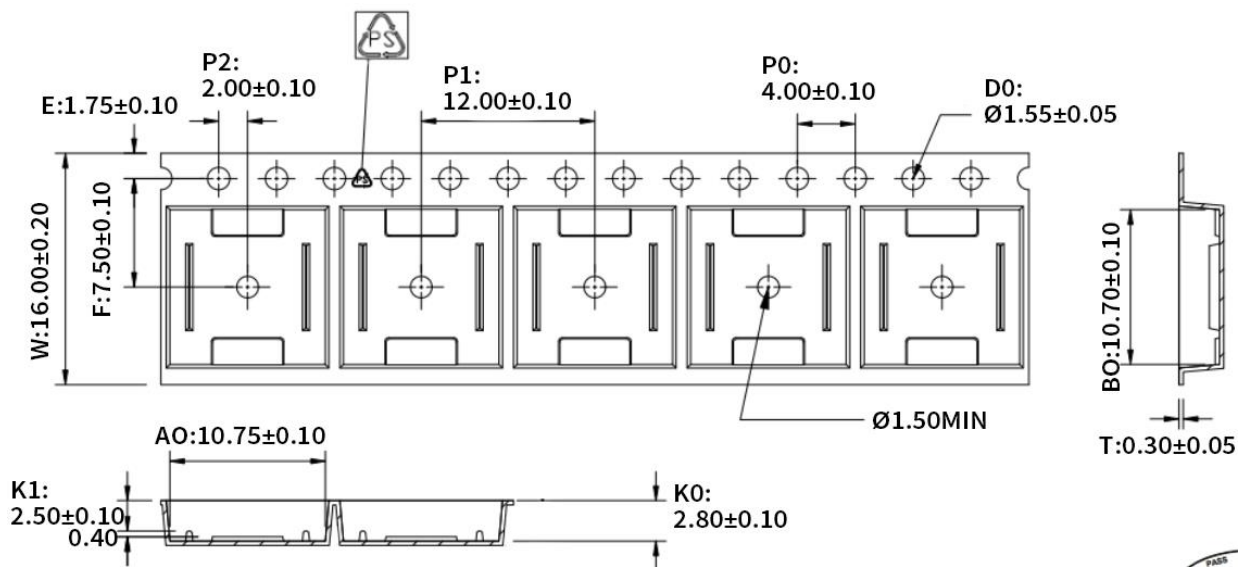


Figure 11.1 Tape and Reel Information of SOP8



| PRODUCT SPECIFICATION |             |             |                                      |             |                                                               |            |
|-----------------------|-------------|-------------|--------------------------------------|-------------|---------------------------------------------------------------|------------|
| TAPE WIDTH            | Ø A<br>±2.0 | Ø N<br>±2.0 | W1                                   | W2<br>(Max) | W3                                                            | E<br>(MIN) |
| 08MM                  | 330         | 178         | 8.4 <sup>+1.5</sup> <sub>-0.0</sub>  | 14.4        | SHALL<br>ACCOMMODATE<br>TAPE WIDTH<br>WITHOUT<br>INTERFERENCE | 5.5        |
| 12MM                  | 330         | 178         | 12.4 <sup>+2.0</sup> <sub>-0.0</sub> | 18.4        |                                                               | 5.5        |
| 16MM                  | 330         | 178         | 16.4 <sup>+2.0</sup> <sub>-0.0</sub> | 22.4        |                                                               | 5.5        |
| 24MM                  | 330         | 178         | 24.4 <sup>+2.0</sup> <sub>-0.0</sub> | 30.4        |                                                               | 5.5        |
| 32MM                  | 330         | 178         | 32.4 <sup>+2.0</sup> <sub>-0.0</sub> | 38.4        |                                                               | 5.5        |

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1. 10 sprocket hole pitch cumulative tolerance  $\pm 0.20$ .
2. Carrier camber is within 1 mm in 250 mm.
3. Material : Black Conductive Polystyrene Alloy.
4. All dimensions meet EIA-481 requirements.
5. Thickness:  $0.30 \pm 0.05$ mm.
6. Packing length per 22" reel: 378 Meters. (Rewind N=122 )
7. Component load per 13" reel: 1000 pcs.
8. Surface resistivity:  $10^5 \sim 10^{10} \Omega/\square$



|    |            |
|----|------------|
| W  | 16.00±0.20 |
| A0 | 10.75±0.10 |
| B0 | 10.70±0.10 |
| K0 | 2.80±0.10  |
| K1 | 2.50±0.10  |

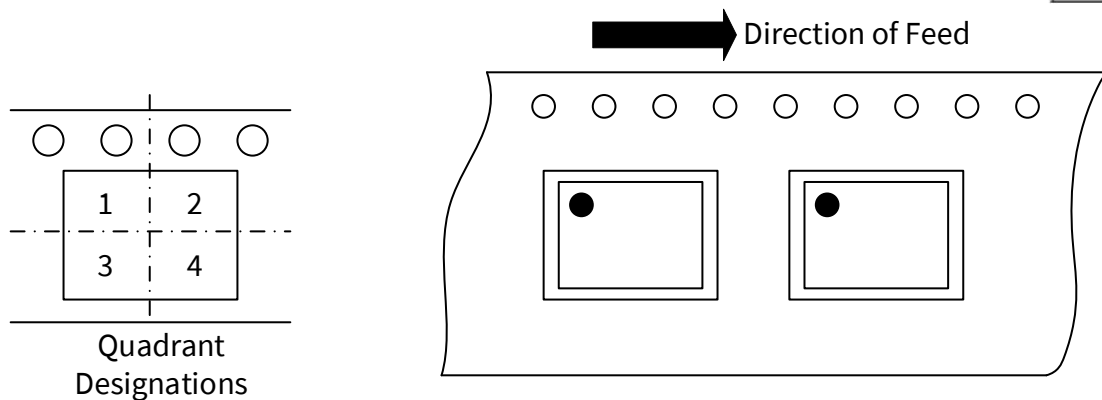


Figure 11.2 Tape and Reel Information of SOW16

### 13. Revision History

| Revision | Description                                                                                                                                                                                                                                                                                 | Date       |
|----------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------|
| 1.0      | Original                                                                                                                                                                                                                                                                                    | 2017/11/15 |
| 1.1      | Change to Ordering information                                                                                                                                                                                                                                                              | 2018/3/26  |
| 1.2      | Add maximum operation current specification.                                                                                                                                                                                                                                                | 2018/6/20  |
| 1.3      | Change block diagram                                                                                                                                                                                                                                                                        | 2018/7/28  |
| 1.4      | Change “Start Up Time after POR” specification to 40us                                                                                                                                                                                                                                      | 2018/8/25  |
| 1.5      | Add “Maximum Input Pulse Voltage”                                                                                                                                                                                                                                                           | 2018/10/9  |
| 1.6      | Change to Ordering information                                                                                                                                                                                                                                                              | 2018/12/20 |
| 1.7      | Change Certification Information, Add “SDA,SCL logic low leakage”                                                                                                                                                                                                                           | 2019/11/15 |
| 1.8      | Add RecommEnded operating conditions                                                                                                                                                                                                                                                        | 2020/2/27  |
| 1.9      | Update format                                                                                                                                                                                                                                                                               | 2021/2/25  |
| 2.0      | Changed MSL                                                                                                                                                                                                                                                                                 | 2021/3/29  |
| 2.1      | Change Tape and Reel Information of SOW16                                                                                                                                                                                                                                                   | 2021/5/24  |
| 2.2      | Corrected NSi8100W MSL to 2                                                                                                                                                                                                                                                                 | 2021/6/28  |
| 2.3      | Change Storage Temperature, Device Information, VIH2/VIL2, V <sub>ILT</sub> comments, Part number. Delete NSi8101. Update Insulation and Safety Related Specifications, add Junction Temperature, update Insulation and Safety Related Specifications part, add Safety-Limiting Values part | 2022/9/7   |

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